

X-Ray Powder Profile Refinement of Zirconium in β -Rhombohedral Boron

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A Rietveld-type full-profile refinement technique, as adapted to Guinier–Hägg strictly $K\alpha_1$ monochromatized X-ray powder-film data (G. Malmros and J. O. Thomas, *J. Appl. Crystallogr.* **10**, 7–11 (1977)), has been used to refine the structure of a solid solution of zirconium in β -rhombohedral boron with composition $ZrB_{\sim 51}$. The space group is $R\bar{3}m$ (No. 166) with hexagonal cell dimensions $a = 10.9564(5)$, $c = 24.0201(13)$ Å, $V = 2497.1$ Å³ and with 309.4 boron atoms per unit cell. The R value roughly comparable to the R_f value of single-crystal work is 0.063. Zirconium atoms partially occupy two non-equivalent holes in the β -boron structure (28% at an $18(h)$ and 18% at a $6(c)$ position).

Introduction

The β -rhombohedral polymorph of boron is invariably formed from the melt at temperatures above 1500°C. It is found to be stable down to room temperature. Appreciable amounts of metal can be dissolved in β -boron, as demonstrated in X-ray investigations of single crystals with compositions $CrB_{\sim 41}$ (1), $CuB_{\sim 28}$, $MnB_{\sim 23}$ (2), $CuB_{\sim 23}$ (3), $FeB_{\sim 49}$ (4), and $ScB_{\sim 28}$ (5).

The β -boron network is only slightly changed by the dissolved metal atoms. However, the unit cell expands and the microhardness increases, a maximum increase of 25% occurring for scandium and manganese (6).

The three largest holes in β -boron (1), denoted by $A(1)$, D , and E , are occupied by metal atoms in various amounts. The $A(1)$ hole is occupied by chromium, manganese, copper, and iron, and the D hole by the same atom types with the addition of scandium. The E hole is occupied by manganese, copper, and scandium. Chromium and copper thus behave differently, despite their equal atomic radii.

Because of the large radius for scandium, the $A(1)$ hole is unoccupied. Scandium also occupies a position between two boron atom sites in the β -boron network, replacing these boron atoms in the structure. The present investigation, using the X-ray powder profile refinement technique, is aimed at discovering how zirconium, with the same atomic radius as scandium (1.60 Å), dissolves in β -boron.

Experiment and Refinement

Crystalline boron (H. C. Starck, Goslar, claimed purity 99.8%) and zirconium turnings (Koch-Light, Colnbrook, claimed purity 99.9% with less than 0.03% O) were melted under purified argon in an arc furnace equipped with a nonconsumable tungsten electrode and a water-cooled copper hearth. The sample, with nominal composition ZrB_{50} , was put into a zirconium diboride crucible and heat treated at 1750°C for 4 hr under 0.5 atm of argon. The sample was crushed in a steel mortar, yielding a powder suitable for the X-ray investigation.

The hexagonal unit-cell dimensions (space group: $R\bar{3}m$, $a = 10.9564(5)$, $c = 24.0201(13)$ Å, $V = 2497.1$ Å³) were determined from a least-squares refinement of θ values obtained from a Guinier-Hägg X-ray powder film. The film was exposed with $\text{CrK}\alpha_1$ ($\lambda = 2.289753$ Å) radiation and with silicon ($a = 5.431065$ Å) as the internal calibration.

A similar film without a calibration standard was taken to provide the profile intensity data. The data were measured with a SAAB Model 2 automatic film scanner (7, 8) coupled on line to an IBM 1800 computer. The data processing and refinement were performed as described at length by Malmros and Thomas (9). Only some special features are referred to here. The conversion from observed transmission values to intensities was made using the expressions $I = 100D(1 + kD)$, and $D = \log_{10}(T_b/T_m)$, where T_b is the background transmission value and T_m the mean transmission value for a given revolution of the film in the scanner. The correction constant k for the nonlinear relative optical density was taken as 0.4. The data evaluation and processing, including a PLG factor correction, was made using the program PILT written by Malmros and Werner (10).

The refinement procedure is essentially the original method of Rietveld (11) for the refinement of neutron powder data adapted for use with the present form of X-ray powder data.

The main difference is that the X-ray film profile is assumed to comprise a superposition of individual line profiles with a modified Lorentzian form. The original Rietveld program uses Gaussian functions.

The characteristic half-width H (in 2θ) is assumed to have a θ dependence given by $H^2 = U \tan^2 \theta + V \tan \theta + W$, where U , V , and W are refinable constants. The refinement minimizes the function Δ :

$$\Delta = \sum_i w_i [y_i(\text{obs}) - K^{-1} \cdot y_i(\text{calc})]^2,$$

where w_i is the weight assigned to an individual observed net intensity $y_i(\text{obs})$, $y_i(\text{calc})$ is the intensity calculated on the basis of the above assumptions, and K is a scale factor. The parameters refined in the final refinements were

(i) *Profile parameters*

U, V, W	Half-width parameters
Z	Zero point (in 2θ)
a, c	Cell parameters
P	Asymmetry parameter

(ii) *Structure parameters*

K	Scale factor
x_j, y_j, z_j	Fractional coordinates for the j th atom
B_j	Isotropic temperature factor for the j th atom
n_j	Occupation factor for the j th atom

TABLE I

THE REFINED STRUCTURAL PARAMETERS IN $\text{ZrB}_{\sim 51}$ ^a

Atom	Position	x	y	z	Partial occupancy (%)
B(13)	18 (h)		Not refined ^b		52.8 (12) ^c
B(16)	18 (h)	0.0521 (23)	0.1043(47)	0.1371(26)	14.5(11)
Zr(2)	18 (h)	0.20108(14)	0.40215(28)	0.17628(14)	27.9(2)
Zr(3)	6 (c)	0	0	0.23441 (36)	18.1(2)

^a Overall thermal parameter $B = 2.61(10)$ Å².

^b Coordinates taken from $\text{ScB}_{\sim 28}$ (5).

^c Estimated standard deviations are given in parentheses and refer to the least significant digits of their respective values.

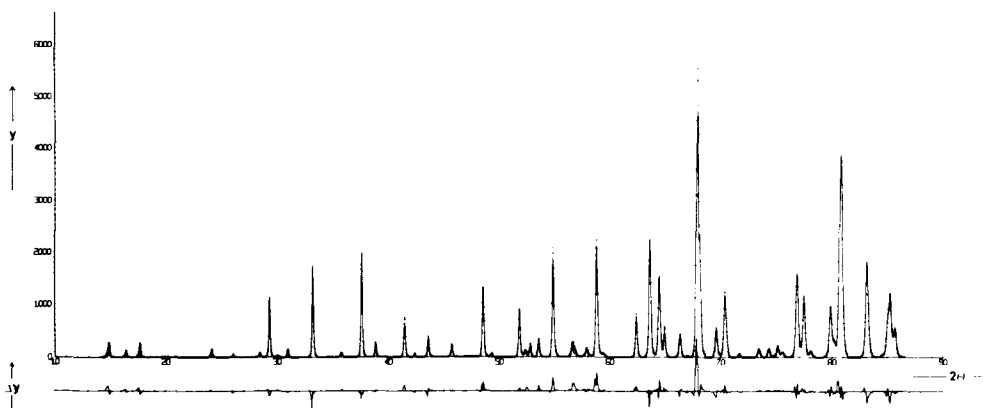


FIG. 1. X-Ray powder profile curve fit for $ZrB_{\sim 51}$. Observed profile; points; calculated profile: continuous line. The lower curve plots the discrepancies on the same scale.

The start values for the positional parameters and the occupation factors were taken from a single-crystal study of $ScB_{\sim 28}$ (5). No satisfactory convergence could be obtained, however, until the occupation factors were allowed to refine for the Zr atoms. In all, 1602 observed intensities with $14.7^\circ < 2\theta < 88.2^\circ$ (92 reflections with a maximum of 7 over-

lapping reflections) were included in the refinement of 18 parameters. The final R values obtained were

$$R_t = \frac{\sum |I_o - K^{-1}I_c|}{\sum I_o} = 0.084,$$

$$R_{\text{profile}} = \frac{\sum |y_o - K^{-1}y_c|}{\sum y_o} = 0.124,$$

$$R_{w,\text{profile}} = \left[\frac{\sum w(y_o - K^{-1}y_c)^2}{\sum wy_o^2} \right]^{1/2} = 0.168.$$

TABLE II
OBSERVED AND CALCULATED X-RAY STRUCTURE FACTORS FOR $ZrB_{\sim 51}$

H	K	L	100*FO	100*FC	H	K	L	100*FO	100*FC
00	00	3	6968	6307	00	00	2	2540	1534
00	00	6	23276	25145	00	00	5	549	1043
00	00	9	959	868	00	00	8	7096	6485
00	00	12	15974	17233	00	00	11	5679	5591
00	00	15	5858	5647	00	00	14	10893	11072
00	00	18	4440	4609	00	00	17	4839	5134
00	00	21	527	1435	00	00	20	9034	8532
00	00	24	9528	9190	00	00	23	1369	1352
00	00	27	2196	2303	00	00	26	1064	1055
00	00	30	3567	3263	00	00	29	3274	3154
00	00	33	3689	3210	00	00	32	3539	3031
00	00	36	12946	13330	00	00	35	297	1222
00	00	39	12103	13885	00	00	38	4059	3652
00	00	42	19700	20378	00	00	41	5854	6378
00	00	45	1708	2430	00	00	44	8227	9430
00	00	48	5333	5390	00	00	47	18242	18283
00	00	51	2683	3559	00	00	50	1804	1951
00	00	54	18710	18793	00	00	53	1549	1505
00	00	57	10425	10867	00	00	56	1708	2430
00	00	60	18520	17146	00	00	59	1961	1982
00	00	63	2303	2208	00	00	62	12441	12024
00	00	66	528	455	00	00	65	715	696
00	00	69	5826	5384	00	00	68	2627	2739
00	00	72	1382	1244	00	00	71	4460	4327
00	00	75	3901	4091	00	00	74	2799	2610
00	00	78	6356	5464	00	00	77	4543	4589
00	00	81	2400	2589	00	00	80	4805	7065
00	00	84	8172	8185	00	00	83	15240	13685
00	00	87	7147	6577	00	00	86	21477	20201
00	00	90	5284	5029	00	00	89	11113	11099
00	00	93	1379	1309	00	00	92	2870	2327
00	00	96	4924	8221	00	00	95	10702	10212
00	00	99	3883	3657	00	00	98	116	68
00	00	102	3617	1850	00	00	101	6074	5305
00	00	105	4104	4244	00	00	104	11458	10931
00	00	108	388	1138	00	00	107	3666	3887
00	00	111	1179	1109	00	00	110	11113	11739
00	00	114	3280	3056	00	00	113	393	1328
00	00	117	8156	7958	00	00	116	815	904
00	00	120	5299	4142	00	00	119	6535	6503
00	00	123	6000	6266	00	00	122	2877	2327
00	00	126	4724	4808	00	00	125	3244	3385
00	00	129	393	1328	00	00	128	6665	6260
00	00	132	1293	1571	00	00	131	19115	18750
00	00	135	7364	7806	00	00	134	1928	1818

Here, I denotes the integrated intensity of a reflection. An R value roughly comparable to the R_f value of single-crystal work was 0.063. The final positional and thermal parameters are given in Table I, and the final profile fit is shown in Fig. 1. A list of observed and calculated structure factors is given in Table II.

Atomic scattering factors used for Zr and B were those of Hanson *et al.* (12). No correction was made for anomalous dispersion.

Discussion

The structure of β -boron and the holes which metal atoms have been found to occupy were described earlier (2, 5, 13, 14). Only the special features of $ZrB_{\sim 51}$ are discussed below.

Positional parameters for only one boron atom, B(16), and the two zirconium atoms have been refined. We thus have no basis for a discussion of metal-boron and boron-boron

TABLE III

UNIT CELL DIMENSIONS FOR β -BORON $ZrB_{\sim 51}$ AND $ScB_{\sim 28}$ AS OBTAINED FROM POWDER SPECIMENS

	<i>a</i>	<i>b</i>
β -Boron ^a	10.9253(5) Å	23.8103(16) Å
$ZrB_{\sim 51}$	10.9564(5)	24.0201(13)
$ScB_{\sim 28}$ ^b	10.9620(7)	24.0752(27)

^a Reference (1).^b Reference (5).

distances. However, zirconium can be assumed to expand the β -boron network in the same way that scandium expands it, since the two metals dissolve in qualitatively similar manners. The lower metal content in $ZrB_{\sim 51}$ compared to $ScB_{\sim 28}$ is demonstrated by its smaller unit-cell dimensions; see Table III.

The metal atoms in $ZrB_{\sim 51}$ partially occupy two different crystallographic positions. The Zr(2) atoms have a 28% occupancy of the *D* holes, and have 14 or possibly 15 boron neighbors. The mean Me(2)–B distances in the earlier MeB_x structures studied are 2.40–2.44 Å. The centers of six *D* holes form a slightly puckered hexagonal ring with B(15) at its center. The distance between adjacent *D* holes is ~ 2.5 Å, which is too short for zirconium atoms. Only nonadjacent positions can thus be occupied; see Fig. 2. In $ScB_{\sim 28}$ and the other MeB_x structures, the boron neighbor closest to Me(2) is B(13). A high Me(2) occupancy or a

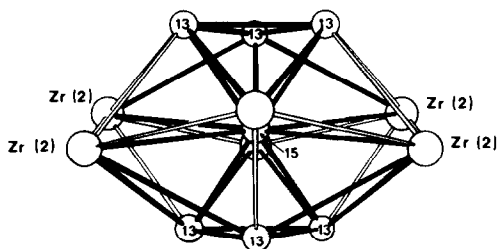


FIG. 2. A perspective view of B(15) and the surrounding B(13) and Zr(2) positions. The *c* axis is vertical in the plane of the paper and passes through B(15). Short Zr(2)–B(13) and Zr(2)–Zr(2) distances are unfilled.

large atomic radius for Me(2) seems to decrease the occupancy of the B(13) positions from 73% in β -boron to approximately 63% in $ScB_{\sim 28}$, $CuB_{\sim 28}$, and $MnB_{\sim 23}$. This effect is also seen in $ZrB_{\sim 51}$; the B(13) occupancy here is 53%.

The other metal atom, Zr(3), occupies the *E* hole. The Zr(3) atom has 15 boron neighbors, and the mean Me–B distances in the other structures are 2.45–2.46 Å. See Refs. (2, 5) for descriptions of the β -boron structure and the metal positions.

The A(1) hole has been found not to be occupied by zirconium; it is clearly too small, with mean Me–B distances in other MeB_x structures of 2.15–2.16 Å.

The B(16) position is found to be occupied to 14% in $ZrB_{\sim 51}$, although it was unoccupied in $ScB_{\sim 28}$. The largest B(16) occupancy (25%) has been found for β -boron itself. Factors other than space restrictions clearly control the occupancy of this position.

In an additional refinement, the occupancy of the Zr(4) position was found to be insignificantly low (0.7(2)%). This position has been found to be occupied in the case of scandium, where the Me(4) atom is situated close to the center of the line joining two neighboring boron atoms. The two boron atoms are replaced by the metal atom at an intermediate position.

Despite the apparently low *R* value (0.063), the standard deviations obtained are large and are probably underestimated. This is due both to the limited number of reflections (92) and to the rather special character of the curve-fitting technique used here. Furthermore, no anomalous dispersion correction has been made for the zirconium atoms, a factor which could affect the refined zirconium occupancies. Nevertheless, in spite of these limitations, the method used has been shown to give a reasonably accurate result in this investigation. The accuracy, although not as high as the accuracies obtained with single-crystal methods, does represent an average taken over a much larger sample.

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